

















Features

- 1.65"x0.88" compact size
- Medical safety approved (2 x MOPP) according to ANSI/AAMI ES60601-1 and IEC/EN60601-1
- Suitable for BF application with appropriate system consideration
- No load power consumption<0.075W
- Extremely low leakage current
- Wide operating temp. range -30 ~ +85°C
- EMI class B for class II configuration
- · Protections: Short circuit / Overload / Over voltage / Over temperature
- No minimum load required
- 3 years warranty

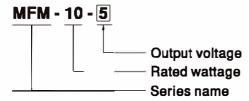
Applications

- Portable medical device
- Mobile clinical workstation
- Medical computer monitor
- Medical examination instrument

Description

MFM-10 is a 10W high density and small size (42*22.3*20.5mm) AC/DC on board type medical grade power supply series. It features the operation for 80~264VAC, a low no load power consumption less than 0.075W, a high efficiency up to 84%, Class II (no FG) double insulation, outstanding dissipation, 5G anti-vibration, high EMC performance, 4KVAC isolation, etc. The design observes IEC/EN60601-1 and ANSI/AAMI ES60601-1 version three with 2xMOPP level and ultra-low leakage current (<80 μ A). It is very suitable for BF (patient contact) type medical device or relevant equipment.

Model Encoding

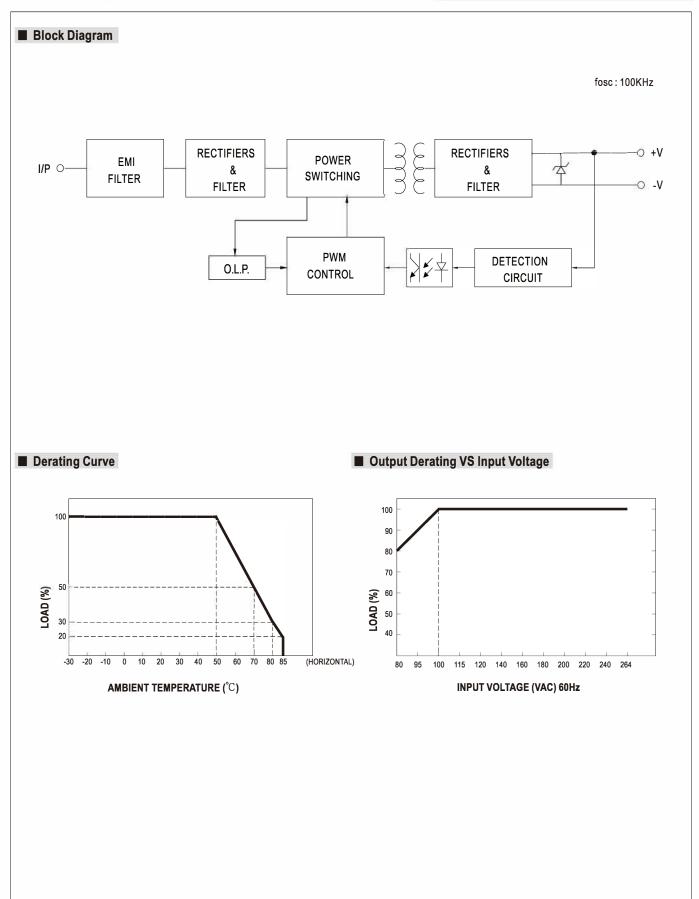




SPECIFICATION

		MFM-10-3.3	MFM-10-5	MFM-10-12	MFM-10-15	MFM-10-24
	DC VOLTAGE	3.3V	5V	12V	15V	24V
	RATED CURRENT	2.5A	2A	0.85A	0.67A	0.42A
	CURRENT RANGE Note.2	0 ~ 2.5A	0~2A	0 ~ 0.85A	0 ~ 0.67A	0~0.42A
	PEAK CURRENT	2.75A	2.2A	0.94A	0.74A	0.46A
	RATED POWER	8.3W	10W	10.2W	10W	10W
	PEAK LOAD(10sec.) Note.3	9W	11W	11.3W	11.1W	11W
	RIPPLE & NOISE (max.) Note.4		100mVp-p	180mVp-p	180mVp-p	200mVp-p
OUTPUT	VOLTAGE TOLERANCE Note.5		±2.5%	±2.5%	±2.5%	±2.5%
	LINE REGULATION	±0.3%	±0.3%	±0.3%	±0.3%	±0.3%
	LOAD REGULATION	±0.5%	±0.5%	±0.5%	±0.5%	±0.5%
	SETUP, RISE TIME	1000ms, 30ms/230VAC 1000ms, 30ms/115VAC at full load				
	HOLD UP TIME (Typ.)	40ms/230VAC 8ms/115VAC at full load				
		80 ~ 264VAC				
	FREQUENCY RANGE	47 ~ 440Hz				
INPUT	EFFICIENCY (Typ.)	78%	81%	83%	83%	84%
51	AC CURRENT (Typ.)	0.3A/115VAC				
	INRUSH CURRENT (Typ.)	COLD START 25A/115VAC 45A/230VAC				
	LEAKAGE CURRENT (max.) Note.7	Touch current <80μA/264VAC				
		110% ~ 180% rated output power				
	OVERLOAD	Protection type: Hiccup mode, recovers automatically after fault condition is removed				
PROTECTION		3.8 ~ 5V	5.75 ~ 6.8V	13.8 ~ 16.2V	17.3 ~ 20.3V	27.6 ~ 32.4V
PROTECTION	OVER VOLTAGE		1			1
	OVER TEMPERATURE	Protection type: Shut off o/p voltage, clamping by zener diode Protection type: Shut down o/p voltage, recovers automatically after temperature goes down				
	WORKING TEMP.	-30 ~ +85°C (Refer to "Derating Curve")				
ENVIRONMENT	WORKING TEMP.	, , ,				
		20 ~ 90% RH non-condensing				
	STORAGE TEMP., HUMIDITY	-40 ~ +100°C, 10 ~ 95% RH non-condensing				
	TEMP. COEFFICIENT	±0.03%/°C (0 ~ 50°C)				
	SOLDERING TEMPERATURE	260°C ±5°C/10sec.max.				
	VIBRATION		cycle, period for 60m	in. each along X, Y, Z axes	3	
	OPERATING ALTITUDE Note.8					-rd
	SAFETY STANDARDS	IEC60601-1, EN60601-1, EAC TP TC 004,UL ANSI/AAMI ES60601-1 (3.1 version), CAN/CSA-C22 3rd Edition approved; Design				
	ICOLATION LEVEL	refer to EN60335-1 Primary-Secondary: 2xMOPP				
	ISOLATION LEVEL					
	WITHETAND VOLTACE		OFF			
	WITHSTAND VOLTAGE	I/P-O/P:4KVAC				
	WITHSTAND VOLTAGE ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50	0VDC / 25°C / 70% RI		Tanklaw	al/Nata
		I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter	0VDC / 25°C / 70% RI	tandard	Test Leve	el / Note
	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted	0VDC / 25°C / 70% RI S	tandard N55011 (CISPR11)	Class B	el / Note
		I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated	0VDC / 25°C / 70% RI S E	tandard N55011 (CISPR11) N55011 (CISPR11)	Class B Class B	el / Note
	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current	0VDC / 25°C / 70% RI S E E	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2	Class B	el / Note
SAFETY &	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated	0VDC / 25°C / 70% RI S E E	tandard N55011 (CISPR11) N55011 (CISPR11)	Class B Class B	el / Note
5	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current	0VDC / 25°C / 70% RI S E E	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2	Class B Class B	el / Note
EMC	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker	0VDC / 25°C / 70% RI S E E E	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2	Class B Class B	
SAFETY & EMC (Note 9)	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2	0VDC / 25°C / 70% RI S E E E E	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3	Class B Class B Class A	el / Note
EMC	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD	0VDC / 25°C / 70% RI S E E E E	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2	Class B Class B Class A Test Level 4, 1	el / Note
EMC	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter	0VDC / 25°C / 70% RI S E E E E	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3	Class B Class B Class A Test Level 4, 1 Level 3, 1	el / Note 5KV air ; Level 4, 8KV contact
EMC	ISOLATION RESISTANCE EMC EMISSION	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD	0VDC / 25°C / 70% RI S E E E E S E	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2	Class B Class B Class A Test Level 4, 1 Level 3, 1	el / Note 15KV air ; Level 4, 8KV contact 10V/m(80MHz~2.7GHz) ~28V/m(385MHz~5.78GHz)
EMC	ISOLATION RESISTANCE	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD RF field susceptibility	0VDC / 25°C / 70% RI S E E E E S E	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2 N61000-4-3	Class B Class A Test Level 4, 1 Level 3, 1 Table 9, 9 Level 3, 2	el / Note 15KV air ; Level 4, 8KV contact 10V/m(80MHz~2.7GHz) ~28V/m(385MHz~5.78GHz)
EMC	ISOLATION RESISTANCE EMC EMISSION	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD RF field susceptibility EFT bursts	0VDC / 25°C / 70% RI	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2 N61000-4-3 N61000-4-4	Class B Class A Test Level 4, 1 Level 3, 1 Table 9, 9 Level 3, 2	el / Note 15KV air ; Level 4, 8KV contact 0V/m(80MHz~2.7GHz) 1~28V/m(385MHz~5.78GHz) 2KV KV/Line-Line
EMC	ISOLATION RESISTANCE EMC EMISSION	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD RF field susceptibility EFT bursts Surge susceptibility	0VDC / 25°C / 70% RI	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2 N61000-4-3 N61000-4-4 N61000-4-5	Class B Class B Class A Test Level 4, 1 Level 3, 1 Table 9, 9 Level 3, 2 Level 3, 1	el / Note 15KV air ; Level 4, 8KV contact 10V/m(80MHz~2.7GHz) 1~28V/m(385MHz~5.78GHz) 2KV KV/Line-Line 10V
EMC	ISOLATION RESISTANCE EMC EMISSION	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD RF field susceptibility EFT bursts Surge susceptibility Conducted susceptibility Magnetic field immunity	0VDC / 25°C / 70% RI	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2 N61000-4-3 N61000-4-4 N61000-4-5 N61000-4-6 N61000-4-8	Class B Class B Class A Test Level Level 4, 1 Level 3, 1 Table 9, 9 Level 3, 1 Level 3, 1 Level 4, 3	el / Note 15KV air ; Level 4, 8KV contact 10V/m(80MHz~2.7GHz) 1~28V/m(385MHz~5.78GHz) 2KV KV/Line-Line 10V 10A/m
EMC	ISOLATION RESISTANCE EMC EMISSION	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD RF field susceptibility EFT bursts Surge susceptibility Conducted susceptibility	0VDC / 25°C / 70% RI	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2 N61000-4-3 N61000-4-4 N61000-4-5 N61000-4-6	Class B Class B Class A Test Level 4, 1 Level 3, 1 Table 9, 9 Level 3, 2 Level 3, 1 Level 4, 3 100% dip	el / Note 15KV air ; Level 4, 8KV contact 10V/m(80MHz~2.7GHz) 1~28V/m(385MHz~5.78GHz) 2KV KV/Line-Line 10V 10A/m
EMC	ISOLATION RESISTANCE EMC EMISSION	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD RF field susceptibility EFT bursts Surge susceptibility Conducted susceptibility Woltage dip, interruption	0VDC / 25°C / 70% RI	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2 N61000-4-3 N61000-4-4 N61000-4-5 N61000-4-6 N61000-4-8	Class B Class B Class A Test Level 4, 1 Level 3, 1 Table 9, 9 Level 3, 2 Level 3, 1 Level 4, 3 100% dip	el / Note 15KV air ; Level 4, 8KV contact 10V/m(80MHz~2.7GHz) ~28V/m(385MHz~5.78GHz) EKV KV/Line-Line 10V 10A/m 1 periods, 30% dip 25 periods
EMC Note 9)	EMC EMISSION EMC IMMUNITY	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD RF field susceptibility EFT bursts Surge susceptibility Conducted susceptibility Woltage dip, interruption	0VDC / 25°C / 70% RI E E E E E E E E H E H H H	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2 N61000-4-3 N61000-4-4 N61000-4-5 N61000-4-5 N61000-4-6 N61000-4-8 N61000-4-11	Class B Class B Class A Test Level 4, 1 Level 3, 1 Table 9, 9 Level 3, 2 Level 3, 1 Level 4, 3 100% dip	el / Note 15KV air ; Level 4, 8KV contact 10V/m(80MHz~2.7GHz) ~28V/m(385MHz~5.78GHz) EKV KV/Line-Line 10V 10A/m 1 periods, 30% dip 25 periods
EMC	EMC EMISSION EMC IMMUNITY	I/P-O/P:4KVAC I/P-O/P:100M Ohms / 50 Parameter Conducted Radiated Harmonic Current Voltage Flicker EN60601-1-2 Parameter ESD RF field susceptibility EFT bursts Surge susceptibility Conducted susceptibility Voltage dip, interruption 1756.2Khrs min. MIL-	0VDC / 25°C / 70% RI E E E E E E E E HDBK-217F (25°C)	tandard N55011 (CISPR11) N55011 (CISPR11) N61000-3-2 N61000-3-3 tandard N61000-4-2 N61000-4-3 N61000-4-4 N61000-4-5 N61000-4-5 N61000-4-6 N61000-4-8 N61000-4-11	Class B Class B Class A Test Level 4, 1 Level 3, 1 Table 9, 9 Level 3, 2 Level 3, 1 Level 4, 3 100% dip	el / Note 15KV air ; Level 4, 8KV contact 10V/m(80MHz~2.7GHz) ~28V/m(385MHz~5.78GHz) EKV KV/Line-Line 10V 10A/m 1 periods, 30% dip 25 periods

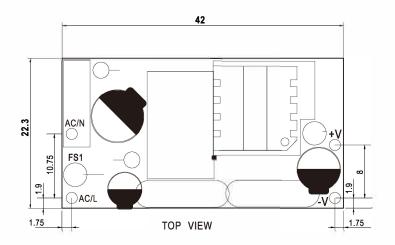


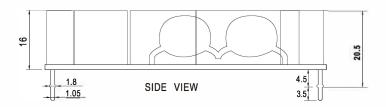




■ Mechanical Specification

Unit:mm





■ Installation Manual

Please refer to : http://www.meanwell.com/manual.html